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(54) Title: BONDING INNER LAYERS IN PRINTED CIRCUIT BOARD MANUFACTURE (57) Abstract A process for manufacturing a multi-layer circuit board comprises applying a layer of a photoresist to the conducting surface of an inner layer and fixing the resin composition in a pre-selected pattern for example by exposing to UV radiation which results in polymerisation in the exposed areas. After removing the non-fixed areas by developing in an aqueous developing solution and etching in an etching solution, the fixed areas of resin composition remain in place on the inner layer and are directly adhered to the neighbouring insulating layer in an adhesion step. The preferred resin compositions according to the invention comprise a first photo-polymerisable resin component having an acid number from 15 to 75, a second epoxy resin component having unreacted epoxy groups, and a photoinitiator, the ratio of first to second resin components being at least 1:1.		

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BONDING INNER LAYERS IN PRINTED
CIRCUIT BOARD MANUFACTURE

Field of the Invention

This invention relates to the manufacture of multilayer printed circuit boards (PCBs).

Background of the Invention

10 In the manufacture of a printed circuit board (PCB),
in a first (multi-step) stage a "bare board" is prepared
and in the second (multi-step) stage, various components
are mounted on the board. The bare board is often a multi-
layer board, generally comprising a first, inner-layer
15 which is usually an epoxy-bonded fibreglass sub-layer clad
on one or more usually both sides, with a conducting sub-
layer. The conducting sub-layer usually comprises
conducting material which is metal foil and most usually
copper. The conducting material is generally a
20 discontinuous sub-layer in the form of the circuit pattern.
On at least one, and generally on both sides of the inner
layer, an outer (or further) layer is attached. An outer
layer will comprise at least a layer of an insulating
material, again, generally epoxy-bonded fibreglass which is
25 bonded to the conducting sub-layer of the innerlayer. The
outer layer may additionally comprise at least one
conducting sub-layer. The outer layer or layers are
insulating layers or are adhered to the conducting sub-
layer of the first inner layer with an insulating layer or
30 sub-layer innermost to the first layer.

A multi-layer board therefore comprises a laminate in
which conducting sub-layers are separated by insulating
layers or sub-layers. The laminates are formed by adhering
layers together. The layers which form the laminate may be
35 conducting or insulating only or more usually are made up
from sub-layers: at least one insulating and at least one
conducting sub-layer. Generally conducting sub-layers are

only provided on an insulating sub-layer due to their fine, fragile nature.

Various difficulties have been noted in trying to permanently bond the copper circuit pattern surface and an insulating organic substrate together. The copper surface tends to oxidise on exposure to the atmosphere to form a tarnished layer on its surface. If the next layer is adhered directly to this tarnished layer of copper, the bond will be weak and eventually will fail.

The most commonly used method for overcoming this problem is to remove the tarnish layer and form a strongly adherent copper oxide layer.

A process is described below, with reference to the accompanying Figures 1A to 1G to show a conventional negative working type of process for making this type of multi-layer board. In this example, the inner-layer (or first layer) comprises an insulating sub-layer having a conducting sub-layer on each side and the outer layers (or second layers) are insulating only. Although other conductive materials may be used in this type of process, the conducting sub-layers in this example comprise copper foil. The insulating layers in this example are epoxy-bonded fibreglass. The material of the outer layers is known as pre-preg and generally comprises a higher proportion of epoxy resin relative to the fibre glass than the sub-layer of the inner layer.

The inner-layer 1, (illustrated in Figure 1A), comprising insulating sub-layer 2 and copper foil layers, 3 is coated on each side with a light-sensitive film 4 (shown in Figure 1B) which is exposed to light in pre-selected areas. The unexposed film is then removed by developing to leave a pre-selected pattern of exposed copper 5, as illustrated in Figure 1C. The areas of the copper which are revealed are generally the areas which are to be etched away, to leave the desired circuit pattern of the copper in the pattern corresponding to the cured photo-resist. The unwanted copper areas are then etched away

using a chemical etchant, resulting in the arrangement illustrated in Figure 1D. At this stage, the photo-resist remaining is chemically removed to result in the arrangement illustrated in Figure 1E and the revealed copper surface is cleaned to remove any tarnishing from the copper surface. A black or brown oxide layer 6 is then formed on the cleaned copper surface (as shown in Figure 1F) and then as shown in Figure 1G the two outer layers 8 are then placed onto the black or brown oxide coatings on each side of the inner-layer, respectively. The laminate is then formed by pressing the layers together and applying heat so that the insulating sub-layer (pre-preg material) of outer layers 8 flows and provides adhesion to the brown or black oxide coating.

Additional conducting sub-layers (or cap layers), may also be added to the laminate. To do so, an additional layer comprising a conducting sub-layer, generally copper which has been pre-treated by a passivation step for example a zinc, tin, chromium or molybdenum passivation step is placed onto the outside of the pre-preg, prior to applying pressure and heat. On application of heat and pressure, the pre-preg (outer layers) adheres to the inner-layer and the additional layers adhere to the pre-preg substantially simultaneously.

Thus, as will be seen from the description above, generally, after etching and removal of the photo-resist layer, the exposed copper surface which is in the form of a circuit pattern, is cleaned to remove the tarnish layer and then the copper surface is immersed in hot, strongly alkaline, hypochlorite solution generally at temperatures of around 40 to 110°C. This results in the formation of the "black or brown oxide" layer which not only forms a strong bond with the copper surface but also has a high surface area so that organic films such as adhesives for laminating layers in a multi-layer circuit board can be bonded with a strong bond.

However, this process may be problematic because the formation of the black oxide layer must be carefully controlled to ensure formation of a coating which will give good adhesion after lamination. Furthermore, these black oxide layers are subject to attack by solutions which dissolve copper oxide such as the pre-treatment solutions for the electroless plating processes which are often acidic. The dissolution of the copper oxide may result in delamination. This problem is known as "pink ring" because a pink ring of copper can be seen in the black oxide coating on the copper.

Attempts have been made to overcome these problems by adapting the oxide coating. The most commonly used procedure is to incorporate an additional reducing step, further complicating the process.

An alternative coating method has been described in EP-A-0,275,071 where after etching and then removal of the photo-resist, the copper surfaces are, as in the usual processes cleaned to remove any traces of tarnish, but after cleaning instead of forming a black oxide layer, a primer for the adhesive is applied directly to the copper. The primer comprises a layer of poly(vinylacetal)-phenolic resin. This process largely follows the conventional preparation process and simply provides an alternative for black oxide.

Therefore, as with the black oxide type processes, the process is lengthy and requires a large number of production steps.

It is known to use meth(acrylate)-based resins for forming the photo-resist, for example, see GB-A-2193730. However, the photo-resist compositions described in this reference are for use in conventional processes where the resist is removed prior to cleaning of the copper surface and preparation for lamination as described above.

It is also known to use epoxy-acrylate- or acrylate-based resins for forming a solder mask. The solder mask is used at a later stage in the bare board manufacture when

the bare board is almost complete and the outer surfaces are being prepared for passing to the next component attachment stage. These types of solder mask are described in "Fine Line Resolution Solder Mask" by S. Rodriguez and
5 K. Cheethan published in the Proceedings of the EIPC Winter Conference (PCB Applications: New Processes, OEM and Far East Challenges) Zurich 11.12.91 p. 3-4-1 to 3-4-7.

EP-A-51,630 also describes an epoxy-acrylate solder mask composition and EP-A-515,861 describes epoxy-based
10 inks which are used to form a protective coating on circuit boards.

However, in all of these references, the resist or mask provides a protective function only and in particular, the photo-resist after having fulfilled its protective
15 function is removed.

In an attempt to overcome the problems of the prior art systems and to form a simplified process for ensuring good adhesion within the laminated multi-layer PCBs, photo-resists have been developed which after etching of the
20 copper, does not have to be removed, but can remain in place. The pre-preg is then adhered to the remaining photo-resist in the adhesion step.

Such processes for manufacturing multi-layer circuit boards are described in "Elektronik, vol. 29, no. 25,
25 December 1980 p 96-98, "Fotoresist-Basismaterialien vereinfachen Fertigung von Mehrlagen - Leiterplatten" by W.Klose, US-A-4074008 and US-A-3956043 (equivalent to FR-A-2197301). The article by Klose describes the use of an epoxy resin, "Probimer 48" from Ciba Geigy which is
30 described as having photo-crosslinking groups so that in a first step, the resin can be exposed to UV radiation for photocuring and in a subsequent step a thermal hardening reaction is used to form the multi-layer board. In US-A-3956043 and US-A-4074008 photopolymerisable epoxide resins
35 are described which polymerise on exposure to actinic radiation and which can be subsequently crosslinked by heat curing agents for epoxide resins. It is disclosed that

these may be used for forming multi-layer circuit boards and that they do not have to be stripped off but can remain in place. The resins described in US-A-4074008 are said to provide an improvement over the prior art epoxide resins because they have a higher epoxide group content, so provide better adhesion.

Such photo-resists are known as permanent or bonding resists. However, the bonding resists disclosed in each of these references have significant limitations. They have been found to provide PCBs which tend to delaminate. It is thought that this is largely due to "outgassing" on use whereby gases, generally water vapour, become trapped between the layers of the laminate either at the boundary between resist and metal layers, or within the resist itself in particular in humid conditions. On subsequent heat treatment of laminated PCBs for example in a soldering step, outgassing occurs resulting in delamination of the board and/or damage to plated through-holes in the board.

Furthermore, the known permanent (or bonding) resists require organic solvent developing to remove the non-fixed areas of resin in the developing step after UV curing of the resin. The use of organic solvent developing is disadvantageous both because of the safety problems involved and the environmental costs concerned.

The present invention aims to overcome the problems of the prior art systems for multi-layer board manufacture.

Summary of the Invention

The present invention provides a process for manufacturing a multi-layer circuit board comprising obtaining a first layer which comprises at least one insulating sub-layer and at least one conducting sub-layer; applying a layer of a resin composition to the surface of the conducting sub-layer; in a fixing step, fixing the resin composition in a pre-selected pattern to form selectively a fixed pattern of

resin composition which is etch-resistant and a non-fixed pattern of resin composition;

then in a developing step, contacting the non-fixed pattern of resin composition with an aqueous developing solution to effect removal of the non-fixed pattern of resin thereby revealing the areas of conducting sub-layer for etching;

etching the revealed areas of conducting sub-layer by contact with an etchant;

contacting an insulating second layer with the fixed, etch-resistant resin composition; and

in a final adhesion step, adhering the first and second layers to one another.

In accordance with the present invention, there is also provided a multi-layer circuit board comprising a first layer, etch-resistant resin and an insulating second layer in which the first layer comprises an insulating sub-layer and a conducting sub-layer, the first layer being adhered to an insulating second layer so that the etch-resistant resin composition is in direct contact with both the conducting sub-layer and the insulating second layer, and wherein the etch-resistant resin composition is formed from a resin composition comprising a first resin component comprising photopolymerisable groups and having an acid number of from 15 to 75, a second resin component comprising unreacted epoxy groups and a photoinitiator, the weight ratio of first resin component to second resin component being at least 1:1, preferably at least 3:2.

Thus, it has been found that according to the process of this invention, a multi-layer board having good adhesion can be formed in a considerably simplified process. The multilayer boards produced have good adhesion even on exposure to thermal shock conditions, such as in one or more subsequent soldering steps.

Compared with the prior art processes, the process of the present invention enables the etch-resistant resin, generally a photo-resist, to remain in place and to take

part in the adhesion of the two layers so that the process steps involved in forming a multi-layer PCB can be considerably reduced: steps of removing the etch-resistant resin, cleaning the exposed copper surfaces, and applying
5 a primer (either copper oxide or some other layer) prior to laminating the layers together, can all be omitted. Organic solvents are not required in the developing step, thereby reducing safety and waste disposal problems.

Furthermore, because the process according to the
10 present invention does not require the use of a copper oxide layer, the problem of "pink ring" in the prior art processes does not arise as the adhesion promoter is resistant to the plating processes.

15 Detailed Description of the Invention

The first layer is the inner-layer of a circuit board and may comprise one insulating sub-layer having a conducting sub-layer (generally copper foil) on one side only, or on each side. The insulating second layer is
20 sometimes referred to as an outer layer in the PCB industry, generally being a prepreg layer. Where the inner-layer has two conducting sub-layers, the bonding resist may be applied to both conducting sub-layers as described in the process above and two outer layers may be
25 applied, one to each of the conducting sub-layers.

As many layers as are required can be built-up into a composite, multi-layer. However, the general principle is that conducting layers and insulating layers should be alternate.

30 As explained above, the conducting sub-layers in the finished multi-layer board, will generally not comprise continuous conducting material as they are generally the discontinuous pattern of conducting material remaining after etching, in the form of a circuit pattern.

35 In the process of this invention, the resin composition is applied to the surface of the conducting sub-layer by any conventional means. Generally, the resin

composition will be in a liquid form, for example having a viscosity of from 50 to 10,000, preferably greater than 100 and most preferably greater than 500 cps. Where the resin composition is supplied in the form of a liquid, the viscosity will generally be below 2000, or even 1500 cps. Liquid resin compositions can be applied by any conventional coating technique such as screen printing, roller coating, electrostatic spraying or curtain coating. The appropriate viscosity can be selected for the chosen application method, or vice versa. More viscous liquids are used for screen printing than for example spraying, dip coating or curtain coating application techniques. Alternatively, the composition may be applied in a dry form, for example a pre-formed layer may be prepared on a support film and then adhered to the conducting layer in a method conventional for photo-resists, for example as described in GB 2,193,730, the supporting layer then being removed.

Generally, prior to application of the resin composition to the conducting sub-layer, the conducting sub-layer undergoes a pre-treatment cleaning step. The cleaning step may be either a mechanical cleaning step such as brushing or pumice scrubbing, or a chemical step in which the conducting sub-layer is contacted with a chemical cleaning composition which is generally an acidic composition.

After application of a liquid resin composition, there will generally be a drying step in which any solvent is driven off, leaving a dry layer of photo-resist resin composition. The dry coating thickness of the resin composition is generally from $3\mu\text{m}$ to $50\mu\text{m}$, preferably from $7\mu\text{m}$ to $20\mu\text{m}$. It has been found that at dry resin thicknesses below $7\mu\text{m}$, the cover over the conducting sub-layer may be unreliable so that the conducting layer may break through. Whilst resist thickness of greater than $20\mu\text{m}$ may be provided, they have not been shown to give any additional benefit and may tend to cause bond failure after formation

of multi-layer laminate. Preferably, the coating thickness will be at least $9\mu\text{m}$ and most preferably at least $10\mu\text{m}$. Preferably the thickness of the resin composition will be no greater than $18\mu\text{m}$, preferably no greater than $15\mu\text{m}$.

5 The drying step is generally carried out by exposing the coated first layer to hot air, for example by passing coated first layers through a forced air dryer, or otherwise exposing to forced air drying. Generally the drying temperature will be no greater than 120°C ,
10 preferably no greater than 100°C and most preferably no greater than 90°C and should not be so high and/or for such length of time to activate the adhesion step prematurely.

 In the fixing step, the resin composition is fixed to form selectively non-fixed and fixed etch-resistant areas
15 by selective exposure to or contact with a reaction promoter for the resin composition.

 Preferably the resin composition is a radiation-curable composition and the reaction promoter is radiation, such as electron beam curing or actinic radiation and most
20 preferably UV light. The fixed, etch-resistant pattern preferably forms in the areas which are contacted with or exposed to the reaction promoter so that the areas not contacted or exposed to the reaction promoter form the non-fixed pattern. This is a conventional negative working
25 process. Alternatively, the fixed etch-resistant pattern may form from the areas of the resin composition which are not contacted with or exposed to the reaction promoter. In this case, the reaction promoter produces a reaction in the areas of resin composition which are exposed or contacted
30 with it, the reaction resulting in those areas of the resin composition becoming soluble in a developing liquid used in the developing step for removing the non-fixed pattern. This latter process is known as positive working.

 Preferably the fixing step is a negative working step
35 where the reaction promoter produces polymerisation or any other curing which fixes the areas of the resin composition exposed to, or contacted with the reaction promoter.

In the developing step, the non-fixed areas of the resin composition are removed leaving a pattern of fixed, etch-resistant resin composition and a pattern of exposed conducting sub-layer. Alkaline developing and solvent developing are well known developing techniques for conventional photo-resists which are stripped off prior to adhesion of various layers to form a multilayer or PCB. Alkaline developing solutions are aqueous and may comprise a weak alkali such as for example potassium carbonate or a solvent developing solutions may comprise a solvent such as butyl diglycol. An example of solvent developing is given in EP-A-514,630. An example of aqueous alkaline development is described by Rodriguez and Cheetham (referenced above) specifically for protective solder masks.

As explained above, organic solvents tend to be problematic. However, the known bonding resists, as well as tending to provide inadequate lamination especially on exposure to heat shock conditions, are all dependent on organic solvent developing. In the present invention for bonding resists however, this problem can be overcome and the developing solutions may be aqueous alkaline developing solutions, comprising one or more weakly alkaline salts such as alkali metal carbonates, preferably potassium or sodium carbonate. Generally the concentration of the weakly alkaline salt will be from 0.5-20% by weight, generally around 0.5-5% by weight in the aqueous developing solution.

In the developing step, the developing solution generally contacts at least the non-fixed areas of the dry resin composition. Contact may be by any conventional means but is generally by immersion or spraying with the developing solution, generally by spraying. The developing step is carried out for sufficient time to enable the non-fixed areas of the resin composition to be removed from the conducting sub-layer, revealing the areas of conducting

sub-layer for etching and the fixed (cured) pattern of resin composition which is etch-resistant.

As explained above, in a preferred process of the invention, the reaction promoter is light, especially UV light and the process is a negative working process. Thus, in accordance with a preferred process of the present invention, a multi-layer circuit board is manufactured, the process comprising: obtaining a first layer which comprises at least one insulating sub-layer and at least one conducting sub-layer; applying a layer of a resin composition to the surface of the conducting sub-layer; in a fixing step, exposing the resin composition in a pre-selected pattern to light, preferably UV light, to produce a reaction in the resin composition which forms a fixed pattern of resin composition in the areas exposed to light and a non-fixed pattern of resin composition remaining in the areas of the resin composition which have not been exposed to light; then in a developing step, contacting the non-fixed pattern of resin composition with an aqueous developing solution to effect removal of the non-fixed pattern of resin thereby revealing the areas of conducting sub-layer for etching; etching the revealed areas of conducting sub-layer by contact with an etchant; contacting an insulating second layer with the fixed resin composition; and in a final adhesion step, adhering the first and second layers to one another.

Where the developing step tends to soften the exposed parts of the resin, optionally a post-development bake step may be included in the process to increase hardness of the fixed areas of photo-resist resin. This may be necessary to increase the etch-resistance of the resin prior to contact of the assembly with etchant to remove the unwanted areas of conducting sub-layer.

However, if this step is required, it is important that the post-development bake does not reach temperatures which will substantially activate any latent catalyst which may be present in the resin composition for the adhesion

step, or otherwise activate the resin composition prematurely so that it will not adhere in the subsequent adhesion step. Preferably therefore if necessary, the post-development bake should not exceed temperatures above 100°C, most preferably it should not exceed temperatures above 80°C.

Prior to contact with the etchant, the fixed areas of resin composition will be etch-resistant so that they are resistant to an etchant at least for the time taken to etch away the unwanted areas of conducting sub-layers to form the circuit pattern of the first layer. Several different chemical types of etchant are known and used; preferably the etch-resistant resin composition is resistant to more than one type of etchant or even to all types. A preferred etch-resistant composition is resistant to acidic etchant which may comprise for example iron II chloride or copper chloride. An additional preferred composition is resistant to alkaline etchant which may be for example based on ammonium compounds, such as a copper ammonium chloride complex in aqueous ammonia.

Following etching of the exposed pattern of conductive material, the second layer(s), generally one or more prepreg layers are placed adjacent the etch-resistant composition which remains in place on top of the remaining pattern of conducting sub-layer and the two layers adhered to one another in the adhesion step. Generally, the composite is exposed to heat in an adhesion step which initiates the adhesion reaction.

In the adhesion step the bond strength between the copper or other conducting sub-layer is generally enhanced due to enhanced cross-linking within the resin; a bond forms between the resin composition and insulating, second layer both due to reaction in the resin composition, generally cross-linking, and mechanical bonding due to intermixing of the resin composition and the insulating, second layer due to any heat applied in the adhesion step.

Generally, pressure is also applied by placing layers

which are to be formed into a multi-layer laminate of at least the first and second layers, in a press. Where pressure is applied it is generally from 100 to 400 psi, preferably from 150 to 300 psi. The temperature of this
5 adhesion step will generally be from 100°C to 250°C, preferably from 120°C to 200°C. The adhesion step is generally carried out for any time from 5 minutes to 3 hours, most usually from 20 minutes to 1 hour, but is for
10 sufficient time and pressure and at a sufficiently high temperature to ensure good adhesion between the first and second layers.

During this adhesion step, the resin of the insulating sub-layers (generally epoxy resin) tends to flow ensuring that the areas between the conducting areas of the
15 conducting metal sub-layer revealing the insulating sub-layer of the first layer are filled. This ensures that the conducting sub-layer material is substantially sealed between insulating layers and subsequent penetration of water or air is avoided.

20 In addition in the adhesion step, any latent catalyst is activated so that further hardening of the resin, for example by cross-linking or polymerisation reaction occurs in the resin composition. This ensures good adhesion between the conducting material of the conducting sub-
25 layers and the insulating layer adjacent to it, forming a strong bond between the adjacent layers.

If desired, several layers may be placed together in the final adhesion step to effect lamination of several layers in a single step to form the multi-layer board. As
30 will be seen, the present invention provides a considerably simplified process over the known processes and provides good protection of the copper or other conducting material and good adhesion, whilst overcoming the prior art problems of pink ring.

35 The present invention also includes a resin composition for forming a bonding resist and which is preferably used in the process of the present invention,

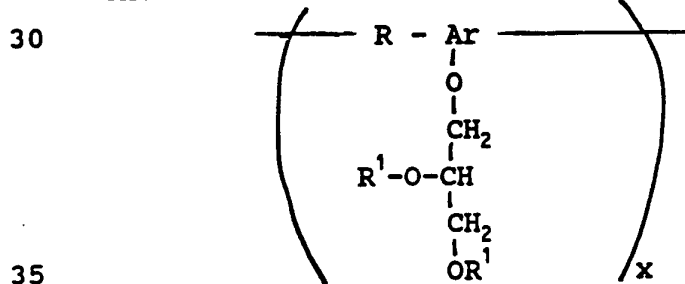
the resin composition comprising a first resin component comprising photopolymerisable groups and having an acid number of from 15 to 75, a second resin component comprising unreacted epoxy groups, and a photoinitiator, the weight ratio of the first resin component to the second resin component being at least 1:1, preferably at least 3:2.

The composition optionally also comprises a latent catalyst.

10 Preferably the acid number of the first resin component is at least 25, more preferably at least 30. Preferably the acid number is no greater than 65 and most preferably no greater than 60.

The acidic groups which produce the desired acid number are preferably carboxylic acid end groups (either branched or terminal end groups) and the ethylenically unsaturated groups are preferably $-C(R^3) = C(R^3)_2$, where the R^3 groups are selected independently from H, C_{1-4} alkyl groups and halogens, although halogens are not preferred. Preferably all three R^3 groups are hydrogen for example in acrylate end groups, or one R^3 group is CH_3 , for example as in methacrylate end groups. The alkyl groups may be optionally substituted, for example with halogens such as chlorine or bromine.

25 The first resin component which comprises photopolymerisable groups is preferably an epoxyacrylate or epoxy (C₁₋₄)acrylate (preferably epoxymethacrylate) or an epoxy resin which is an aromatic polyglycidyl ether having the structural formula I:



in which Ar is an optionally substituted aromatic group having from 1 to 4 phenyl rings;

R is a divalent hydrocarbon group, preferably having from 1 to 10 carbon atoms, most preferably having from 1 to 4 carbon atoms, or -O-, or -N(R²)- (where R² is H or a C₁₋₄ hydrocarbon group, preferably R² is -CH₃), or, less preferably, combinations of these groups; and

R¹ is a combination of H, acidic functional groups and ethylenically unsaturated groups, wherein R¹ is H for no greater than 30% of the total number of R¹ groups, R¹ is an acidic functional group in sufficient proportion to provide an acid number of from 15 to 75, most preferably from 25 to 65, or even from 30 to 60, and the remainder of the R¹ groups being ethylenically unsaturated groups; and x is preferably from 2 to 10.

Where the first resin component comprising photo-polymerisable groups has the formula I above, preferably up to 30% of the R¹ groups are H; from 4-95% of the R¹ groups are acidic functional groups and from 4-95% of the R¹ groups are ethylenically unsaturated groups. Preferably from 25-90% of the R¹ groups are acidic functional groups and ethylenically unsaturated groups, respectively. Preferably the acidic functional R¹ groups are -C(O)-OH and the ethylenically unsaturated functional groups are -CH or CH₃), preferably -CH=CH₂.

The first resin component is substantially free of unreacted epoxide groups. Although the first resin component is preferably an epoxy resin, the first resin component is preferably the reaction product of an epoxy compound so that substantially all the available epoxy groups were reacted during its formation.

The molecular weight of the photo-polymerisable resin, especially where it is formed from the aromatic polyglycidyl ether of the formula I, is preferably no greater than 10,000 and most preferably at least 500 and no greater than 5000, or even no greater than 3000 (as determined by GPC).

Suitable (meth)acrylate resins are any conventionally used for forming conventional photo-resists or solder masks.

5 Suitable examples include unsaturated esters of an epoxy novolac resins are used where the unsaturated acid is (meth)acrylic acid, halogenated (meth)acrylic acid or hydroxyalkyl(meth)acrylate half esters of a di-acid.

10 The photo-initiator is incorporated in the composition to promote reaction of the ethylenically unsaturated groups in the photo-initiated step. The preferred photo-initiators are those which on irradiation, give an excited state that leads to formation of free radicals which then initiate polymerisation of the monomer, such as organic peroxides, hydrogen peroxides, alpha-substituted
15 acetophenones such as 2,2-trichloro-4'-tertiarybutyl acetophenone, benzoylphenylcarbonols and alkyl ethers thereof such as benzene and its alkyl ethers, benzophenones, benzil, acetals and mixtures of phenothiazine dyes or quinoxalines with electron donors.
20 Preferred photoinitiators are benzophenones and/or acyl phosphines.

25 The photoinitiator is generally incorporated in the composition in amounts of from 0.5 to 15% by weight more usually from 1 to 10% by weight of the total resin composition.

30 The second resin component comprises an epoxy resin having unreacted epoxide groups which, in the adhesion step, on conditions of high temperature react to increase adhesion to the surface of the conducting sub-layer (generally copper) and to give good adhesion to the insulating, second layer.

35 The epoxy resin is any resin which contains unreacted epoxide groups and may be for example one or mixtures of more than one of epoxy-novolac resins, bisphenyl A glycidyl ether prepolymers, bisphenol F diglycidyl ether prepolymers or bisphenol H diglycidyl ether prepolymers or epoxy-novolac resins as described in EP-A-514630.

The softening point of the second resin component is preferably from 60-90°C.

The resin composition for use in the present invention should be chemically compatible with the insulating layers in the final laminate produced by adhering the layers together.

Epoxy groups are the preferred functional groups for reacting in the adhesion step, and for forming the backbone in the first resin component because the resin contained in the second insulating layer (prepreg) and often also or sub-layers is generally epoxy-based and therefore the use of epoxy functionality ensures chemical compatibility during the bonding process. Furthermore, epoxy resins are known to have good thermal stability and electrical insulation properties.

The first and second resin components are generally incorporated in the composition of the invention in weight ratios of 2:1 to 6:1, preferably 2:1 to 4:1 and most preferably around 3:1.

Besides the specific first and second resin components mentioned above, the composition of the invention may optionally also comprise one, or mixtures of more than one additional photopolymerisable components to increase the cross-linking density in the resin composition during the adhesion step. The additional photopolymerisable component may be incorporated in the resin composition in amounts up to 25% by weight, but preferably in an amount no greater than 20% or most preferably in an amount below 15% by weight of the total composition. Any photopolymerisable monomer, dimer or oligomer may be used but particularly preferred are multi-functional compounds, such as (meth) acrylates such as TMPEOTA (trimethylol propane ethoxylate triacrylate) and/or TPGDA (tripropylene glycol triacrylate) and/or RCS 88'999 (a urethane acrylate resin) and/or Santolink AM 1150 (melamine acrylate).

The composition will generally contain components to provide a ratio of photopolymerisable to adhesion reactive

epoxy groups of from 2:1 to 10:1, preferably 2:1 to 5:1 and most preferably around 3:1.

The composition preferably comprises 50 - 94% by weight first resin component and 5 to 49% by weight second resin component. More preferably, the composition should comprise from 50 to 89% by weight first resin component and from 10 to 49% second resin component.

The etch-resistant resin composition therefore preferably comprises an organic resin which has reacted in a polymerisation step and a cross-linking step, and in which at least some of the polymerisation or cross-linking has been initiated by exposure to radiation. Particularly preferred etch-resistant resin compositions are those where the cross-linking of the resin is due to reaction of acid groups of an epoxy(meth) acrylate resin with the epoxide groups on a second resin component.

Using such preferred compositions in the process of the present invention, in the photo-initiated reaction step ethylenically unsaturated groups react to increase the average molecular weight of the resin composition producing the fixed areas.

The acidic groups in the resin composition provide aqueous developability and in the developing step, the lower molecular weight non-fixed areas are therefore developed away leaving the fixed areas in place on the conducting sub-layer. In the thermal adhesion step, reaction between the acid groups of the first resin component and the epoxy groups of the second resin component takes place to form a strong bond between the layers. The acidic groups in the resin composition have been found to ensure good contact to the conducting metal sub-layer.

The laminates produced are resistant to delamination even under heat shock conditions and compared with the prior art systems do not suffer from the problem of outgassing at problematic levels. It is postulated that the particularly good properties are due to the fact that

reaction occurs between the two specified resin components which are in an intimate mixture, therefore ensuring reaction throughout the composition and reducing weak spots in the resist and ensuring that substantially no unreacted epoxide groups remain in the bonding resist. This, combined with the acidic nature of the resin composition ensures a particularly effective contact between the surface of the conducting sub-layer and the composition, which appears to minimise moisture uptake, thereby reducing the problem of out-gassing.

It is postulated that out-gassing in the prior art bonding resists may be due at least in part to unreacted epoxide groups in the resin composition which have an affinity for water.

Thus the preferred compositions comprise a first resin component having functional groups effective to photochemically react on exposure to a reaction promoter which is preferably UV radiation, in the fixing step and acidic groups effective to provide aqueous developability in the developing step; photoinitiator for the photo-initiated reaction; a second resin component comprising unreacted epoxide groups effective to react with acid groups on the first resin component in the adhesion step, and optionally latent catalyst to increase the rate of reaction in the adhesion step.

The composition preferably also comprises a latent catalyst for the adhesion step, to increase the rate of reaction in the adhesion step.

The optional latent catalyst is preferably incorporated in amounts up to 5% by weight, most preferably from 0.5 to 4% by weight. Suitable latent catalysts are catalysts for the reaction between the epoxy groups of the second resin component and the acid groups of the first resin component. Examples are blocked catalysts such as amine salts of sulphonic acids eg. morpholine salt of p-sulphonic acid.

A "latent" catalyst is one which remains substantially inactive during the first, photo-initiated polymerisation step, and does not become active as a catalyst for the polymerisation of the functional groups for reaction in the
5 adhesion step, until the adhesion step. Generally, activation of the latent catalyst in the second polymerisation step is by heating at temperatures of above 120°C, or even above 140°C.

The resin composition which may be used in the present
10 invention is generally prepared by mixing the resin components, photoinitiator and any other optional ingredients to form a substantially uniform composition, generally with solvent, such as glycol ethers or glycol ether acetates. Where necessary, fillers and other
15 components may be milled either prior to incorporation in the mixture, which is preferred, or after addition, by milling the final composition.

Optionally the resin composition may also include binder, pigment defoaming agents and other non-interfering
20 additives or fillers.

Examples of the present invention are given below.

Example 1

A composition was prepared by forming a mixture of the
25 following ingredients in the parts by weight quoted in Table 1:

Table 1

	Component	Parts by Weight
5	Albiset A210 (65%) (epoxy acrylate having acid functionality) supplied by Hanse Chemi	480,00
	Novapintviolett A 511 (pigment) supplied by Pinova	12,00
	Syloid ED 20 (filler) supplied by Grace	15,00
10	TMPEOTA (UV-curable trimethylpoly ... component) supplied by Cray Valley	30,00
	RCX 88'999 (UV-curable component) supplied by Rahn	30,00
15	Modaflow (50% in BG) (defoamer/leveller) supplied by Monsanto	30,00
	Talkum Besta 10 (filler) supplied by Luzenac	36,00
	Santolink AM 1150 (UV-curable component) supplied by Monsanto	55,20
20	Butylglycol (solvent)	48,00
	Darocure 1173 (photo-initiator) supplied by Ciba Geigy	12,00
25	Irgacure 651 (photo-initiator) supplied by Ciba Geigy	48,00
	Albiset B202 (epoxy resin) supplied by Hanse	120,00
30	Catalyst SD475 (latent catalyst) supplied by Air Products	9,00

The components were stirred to form a substantially uniform composition.

The composition was then coated onto a pre-cleaned copper foil sheet of an inner-layer for a circuit board by screen printing and the coating was dried to drive off solvent in circulating air at a temperature of 80°C for approx 10 minutes to leave a dried coating, having a thickness of 14µm. Pre-selected areas of the composition were then exposed to UV light by covering with a negative

and passing through a UV-oven so that a pre-selected pattern of the coating only was exposed to UV-light of an intensity of 5 KW for 30 seconds. The unexposed areas of the film were then removed by alkali-developing by
5 immersing in a 2% aqueous solution of sodium carbonate at a temperature of 30°C for 30 seconds. The exposed copper areas were then etched using a standard etching composition of ferric chloride and the etched inner layer was washed with water and dried.

10 The inner layer was then dried by forced air drying, and the neighbouring layer of the multi-layer board was placed on the remaining photo-resist, with the insulating layer inner most. The two adjacent layers were then placed in a press and a pressure of 250 psi was applied and heat
15 was applied at 150°C for 1 hour. The resulting composite had good adhesion in which the resin in the insulating layer had flowed to form a seal between the two layers.

The adhesion properties were tested according to IPC test method 2.4.6 and the results obtained were
20 substantially the same or better than the prior art laminates.

Example 2

A bonding resist composition was prepared by forming
25 the mixture of components as set out in Table 1 of example 1 with the exception that the 30 parts by weight TMPEOTA was replaced with 30 parts by weight TPGDA UV-curable monomer. In use, as described in example 1, the composition shows a slower UV-response than the composition
30 of example 1 because the TPGDA is difunctional rather than trifunctional (TMPEDTA). However, curing is still achieved by exposure to UV-light of an intensity of 5KW for 40 seconds. Good bonding resist properties were obtained.

35 Example 3

A bonding resist composition was prepared as described in example 1, with the exception that the Novapint Violet

A511 pigment was replaced with 2.0 parts by weight. Savinyl Violet[™] pigment (supplied by Sandoz), and the amount of Syloid ED20[™] of filler was increased from 15 to 30 pbw. Again good bonding resist properties were obtained
5 when the composition was used to form a multi-layer board, as described in example 1. It was noticed that dye was adsorbed onto the copper areas during developing of the resist and because of the increased amount of filler, the surface of the resist had a more matt appearance than that
10 of the resists formed as described in examples 1 and 2, respectively.

Example 4

A bonding resist composition was prepared as described
15 in example 1 but with the exception that Albiset B202 was replaced with Albiset XP 9/14. Again, the composition formed an effective bonding resist. It was noted that the composition formed produced a somewhat harder film on drying and required a developing time slightly longer (by
20 10-15%) than the developing time required for the composition of example 1.

Example 5

A composition was prepared as defined in example 1 but
25 with the exception that the 480 pbw epoxyacrylate resin (Albiset A210 (65% active)) of example 1 were replaced with 450 pbw of an epoxymethacrylate resin (PRO 1200 (70% active) supplied by Cray Valley. It was noted that the composition gave a slightly slower UV-response than the
30 composition of example 1. However, cure was still obtained on exposure to UV-light of an intensity of 5 KW for 30 seconds. Good bonding resist properties were obtained.

Example 6

35 Performance tests were carried out on a composition as described in table 1 of example 1, as follows:

Pretreatment

3 sets of innerlayer panels were given different surface preparation as follows:

Set a) Brushed

Set b) Microetched in a 100g/l aqueous solution of sodium persulphate for (1 min) and subsequent acid dip in 5% sulphuric acid for 1 minute, followed by rinsing and drying.

Set c) Pumice scrubbed,

Printing

The panels were then printed with the composition of example using a 120T screen. The panels were transferred into the drying oven directly after printing. The panels were dried at 80°C (circulating air oven), 5 minutes first side, and 10 minutes on the reverse. The panels were completely tack free.

Photo-Curing

Exposure was done using a vacuum frame equipment with a 3KW source.

Optimum exposure time was determined using a Dynachem step wedge, and was found to be about 30 light units (equivalent to 1 min.). This gave a break on the step wedge after development of about 5/6. It was noted that there was only a small change in the break point on the step wedge with a wide range of exposure times. The panels were spray developed in 1% carbonate at 30°C.

Etching

The panels were etched in MacDermid Ac-Cu Guard™ alkaline etchant.

Bonding

The boards were then laid-up as follows:

Board A)

5 $\frac{1}{2}$ oz. Cu Foil

10 Isola 7628 tm (Supplied by Isola) Prepreg

15 Innerlayer with bonding resist

20 Isola 7628 tm Prepreg

25 $\frac{1}{2}$ oz. Cu Foil

Board B)

25 $\frac{1}{2}$ oz. Cu Foil

30 Isola 2113 tm Prepreg

35 Innerlayer with bonding resist

40 Isola 2113 tm Prepreg

45 $\frac{1}{2}$ oz. Cu Foil

45 Some of the innerlayers with bonding resist in place were "baked" at 50°C for 10 min. before pressing to see if this has any beneficial effect.

50 The multi-layer press was a standard Burkle type without vacuum. The press temperature was 171°C with a ram pressure of 71 bar (equivalent to 250 psi on the panels). The overall press cycle was about 1½ hours with 1 hour at maximum temperature and pressure.

After bonding the outer copper was etched away on two panels for the following thermal shock test. The remainder of the panels were sent for drilling and plating.

Thermal Shock

5 One baked and one unbaked panel were tested by repeating cycling in a vertical hot air leveller (solder pot temperature 240°C). After 30 seconds of levelling neither panel showed any sign of delamination. The baked panel was cycled for a further 30 seconds and still showed
10 no signs of delamination.

Example 7

Performance tests were also carried out with composition A (as described in example 4, but with the
15 Albiset A210 replaced by the equivalent weight of Albiset XP9/126) and B (as described in example 4).

Various different layers were obtained, each having a copper foil on each side, each copper foil being 1 oz. per square foot. Inner layers having thickness of the
20 insulating layer of 0.7mm, 0.36mm and 0.2mm, respectively were tested. In addition, inner layers having an insulating layer of thickness of 0.2mm were also tested which had on top of the 1 oz copper or plated copper to provide copper surfaces of up to 2 oz./square foot. All of
25 the inner layer materials used were supplied by B.B Electronics.

Pretreatment

The 0.7mm insulating layer inner layers were pretreated by the mechanical brushing; and the 0.36mm and
30 0.2mm insulating layer inner layers were all pumice scrubbed.

Printing

The panels were printed using the respective compositions A and B, by screen printing using a 100 T
35 polyester mesh. In each case, the screen was double flooded before printing with either composition A or composition B. The panels were dried at 65-70°C

(circulating air oven), for 10 minutes on the first side and eight minutes on the second side.

Photo-curing

The panels were exposed on a Circographic 5000. The
5 inner layers were then exposed for 30 light units equivalent to one minute. This gave a Stuooffler step wedge of copper 8/9.

Developing

The panels were developed using a 1% sodium carbonate
10 solution at 32°C. The panels were then developed at conveyor speed 320mm/minute.

Etching

The panels were then etched in MacDermid ammoniacal etching solution at pH 8.2 and 45°C. Particularly good
15 results were obtained with composition A.

Bonding

The treated inner layers were then bonded in a Burkle open press with the following cycle: four minute gel time at 170°C and 10 bar ram pressure; 70 minute bond time at
20 170°C and 71 bar ram pressure; and 30 minutes cool down time. The final multilayer boards were constructed as shown below.

Four Layer Multilayer

25

0.5 oz. Cu Foil

30

Isola 7628 Prepreg

0.7mm Inner layer with Cu
and photoresist

35

Isola tm 7628 Prepreg

40

0.5 oz Cu Foil

Six Layer Multilayer

5	
	0.5 oz Cu Foil
	Isola tm 2113 Prepreg
10	
	Isola tm 2113 Prepreg
15	0.36mm Innerlayer with Cu and photoresist
	Isola tm 2113 Prepreg
20	
	Isola tm 2113 Prepreg
25	0.36mm Innerlayer with Cu and photoresist
	Isola tm 2113 Prepreg
30	
	Isola tm 2113 Prepreg
35	0.5 oz Cu Foil

Comparative Example

40 **Four Layer Multilayer Using Perstorp TM GE313 UT Innerlayer
from BB Electronics**

45	
	0.5 oz. Cu Foil
	Isola tm 7628 Prepreg
50	
	Isola tm 7628 Prepreg
55	Innerlayer (Perstorp GE313 UT 0.2mm, 2 x 35µm) (BB Electronics)

	Isola 7628 Prepreg
5	
	Isola 7628 Prepreg
10	0.5 oz. Cu Foil

Thermal Shock Testing

The four layer multilayer according to the invention, as outlined above, was prepared using inner layers having photoresist formed from compositions A and B respectively. The four layer board was then given repeated hot air solder levelling in a Cemco Quick Silver machine at 252°C. After 37 seconds of solder immersion, neither board showed signs of delamination. From a comparison of the results obtained using the comparative four layer multilayer, it was concluded that the copper-bonding resist-prepreg bond gives very good adhesion which may be as strong as the copper-prepreg bond in the comparative example. The bond obtained using composition A was particularly good, although no further testing was carried out to determine whether the bond obtained using composition A was stronger than that between copper and the pre-preg in the comparative example.

CLAIMS

1. A process for manufacturing a multi-layer circuit board comprising:

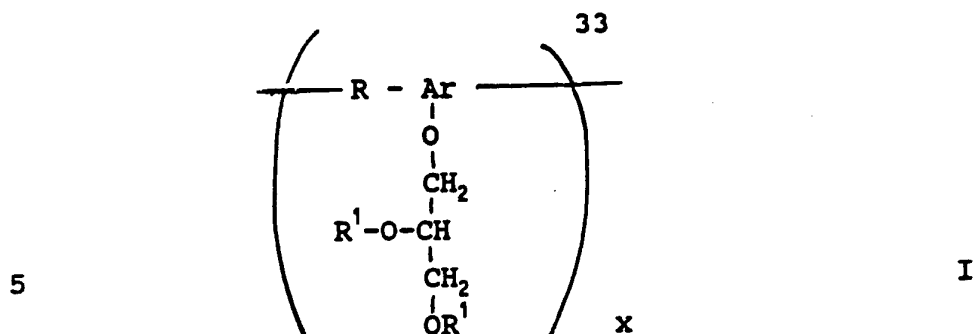
obtaining a first layer which comprises at least one
5 insulating sub-layer and at least one conducting sub-layer;
applying a layer of a resin composition to the surface
of the conducting sub-layer; fixing the resin composition
in a pre-selected pattern to form selectively a fixed
10 pattern of etch-resistant resin composition and a non-fixed
pattern of resin composition; in a developing step,
contacting the non-fixed pattern of resin composition
within aqueous developing composition to effect removal of
non-fixed areas, revealing the areas of conducting sub-
15 layer for etching; etching the revealed areas of conducting
sub-layer by contact with an etchant; contacting an
insulating second layer with the fixed etch-resistant resin
composition; and in a final adhesion step adhering the
first and second layers to one another.

2. A process for manufacturing a multi-layer circuit
20 board comprising obtaining a first layer which comprises at
least one insulating sub-layer and at least one conducting
sub-layer;

applying a layer of a resin composition to the surface
of the conducting sub-layer; in a fixing step, exposing
25 the resin composition in a pre-selected pattern to light,
preferably UV light, to product a reaction in the resin
composition which forms a fixed pattern of resin
composition and a non-fixed pattern of resin composition
remaining in the areas of resin composition which has not
30 been exposed ot light; then in a developing step,
contacting the non-fixed pattern of resin composition with
an aqueous developing solution to effect removal of the
non-fixed pattern of resin thereby revealing the areas of
conducting sub-layers etching; etching the revealed areas
35 of conducting sub-layer by contact with an etchant;
contacting an insulating second layer with a fixed resin

composition; and in a final adhesion step, adhering the first and second layers to one another.

3. A process according to claim 2 in which the resin composition comprises first resin component having functional groups for reacting in the photoinitiated fixing step; functional groups for reacting in the adhesion step; photo-initiator; and optionally, latent catalyst which is substantially inactive prior to the adhesion step in which it is activated to catalyse the adhesion step.
4. A resin composition for a bonding resist comprising a first resin component comprising photopolymerisable groups and acid groups effective to provide aqueous developability, a second resin component comprising unreacted epoxy groups and a photoinitiator.
5. A resin composition according to claim 4 in which the photopolymerisable groups are ethylenically unsaturated groups.
6. A resin composition according to claim 4 or claim 5 in which the first resin component has an acid number of from 15 to 75, preferably the acid number is at least 25, more preferably at least 30 and no greater than 65, more preferably no greater than 60.
7. A resin composition according to any of claims 4 to 6 in which the acidic groups providing the acid number are carboxylic acid end groups and the photopolymerisable groups are ethylenically unsaturated groups selected from $-C(R^3)=C(R^3)_2$, preferably the ethylenically unsaturated groups are part of a (meth)acrylate end group.
8. A resin composition according to any of claims 4 to 7 in which the first resin component comprises an epoxy acrylate or epoxy (C_{1-4}) acrylate (preferably epoxymethacrylate) or an epoxy resin which is an aromatic polyglycidyl ether having the structural formula I given below



in which Ar is an optionally substituted aromatic group having from 1 to 4 phenyl rings;

R is a divalent hydrocarbon group, preferably having from 1 to 10 carbon atoms, most preferably having from 1 to 4 carbon atoms, or -O-, or -N(R²)- (where R² is H or a C₁₋₄ hydrocarbon group, preferably R² is -CH₃); and

R¹ is a combination of H, acidic functional groups and ethylenically unsaturated groups, wherein R¹ is H for no greater than 30% of the total number of R¹ groups,

R¹ is an acidic functional group in sufficient proportion to provide aqueous alkaline developability, preferably to provide an acid number of from 15 to 75, most preferably from 25 to 65, or even from 30 to 60, and the remainder of the R¹ groups being ethylenically unsaturated groups; and

x is preferably from 2 to 10.

9. A resin composition according to claim 8 in which the first resin component comprises an aromatic polyglycidyl ether having the structural formulae (I) in which up to 30% of the R¹ groups are H; from 4-95% of the R¹ groups are acidic functional groups having the formula -C(O)-OH and from 4-95% ethylenically unsaturated R¹ groups of the formula -C(HR)CH₂) = CH₂.

10. A resin composition according to any of claims 4 to 9 in which the second resin component comprises an epoxy resin having unreacted epoxide groups, preferably selected from one or mixtures of more than one epoxy-novolac resins, bisphenol A glycidyl prepolymers, bisphenol F diglycidyl ether prepolymers or bisphenol H diglycidyl prepolymers.

11. A resin composition according to any of claims 4 to 10 in which the second resin component has a softening point of from 60-90°C.

12. A resin composition according to any of claims 4 to 11 in which the weight ratio of first resin component to second resin component is from 1:1 to 6:1 and is preferably at least 3:2.
- 5 13. A process according to any of claims 1 to 3 which the resin composition comprises a resin composition as defined in any of claims 4 to 12.
- 10 14. A multi-layer circuit board comprising a first layer, etch-resistant resin and an insulating second layer in which the first layer comprises an insulating sub-layer and a conducting sub-layer, the first layering being adhered to an insulating second-layer so that the etch-resistant resin composition is in direct contact with both the conducting sub-layer and the insulating second layer, and wherein the
- 15 15. Use of a resin composition according to any of claims 4 to 12 as a photo-resist and additionally, as an adhesive in the manufacture of a multi-layer circuit board.

Fig.1A.

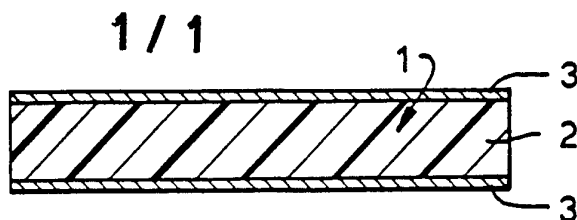


Fig.1B.

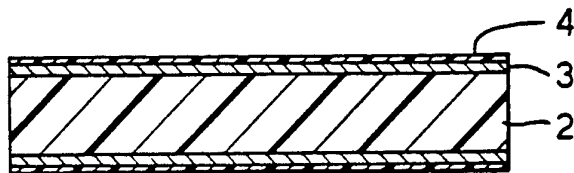


Fig.1C.

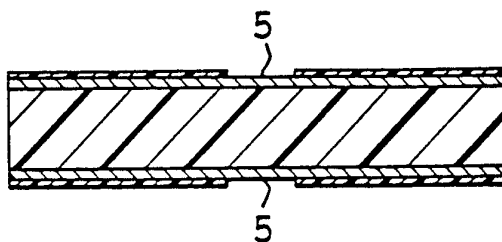


Fig.1D.

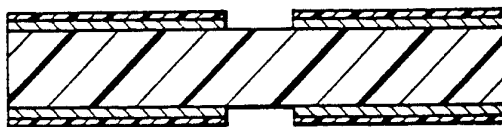


Fig.1E.

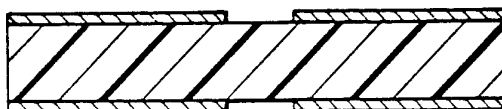


Fig.1F.

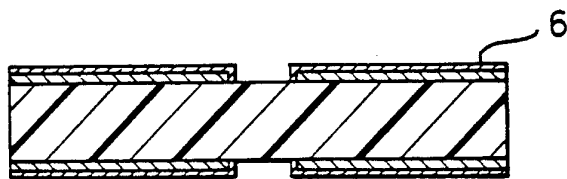
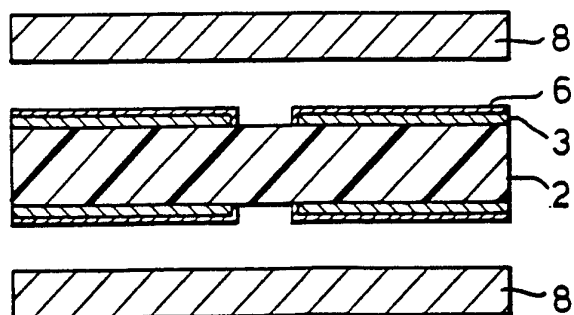


Fig.1G.



INTERNATIONAL SEARCH REPORT

Intern. Application No

PCT/GB 94/02258

A. CLASSIFICATION OF SUBJECT MATTER
 IPC 6 H05K3/46 H05K3/38 G03F7/038

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)

IPC 6 H05K G03F

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
Y	US,A,3 956 043 (ZAHIR ET AL.) 11 May 1976 cited in the application see claims ---	1-15
Y	EP,A,0 323 563 (TAIYO INK MANUFACTURING CO.) 12 July 1989 ---	1-15
A	US,A,4 074 008 (GREEN) 14 February 1978 cited in the application see the whole document --- -/--	1,2, 13-15

☒ Further documents are listed in the continuation of box C.

☒ Patent family members are listed in annex.

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Date of the actual completion of the international search

30 January 1995

Date of mailing of the international search report

03.02.95

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 Fax (+31-70) 340-3016

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Mes, L

INTERNATIONAL SEARCH REPORT

Inter. nal Application No

PCT/GB 94/02258

C.(Continuation) DOCUMENTS CONSIDERED TO BE RELEVANT

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A	DE,A,39 25 895 (FUJI PHOTO FILM CO.) 15 February 1990 see claims ---	1-12
A	US,A,5 009 982 (KAMAYACHI ET AL.) 23 April 1991 see claims ---	1-12
A	EP,A,0 403 170 (MORTON INTERNATIONAL) 19 December 1990 see claims ---	1-12
A	DE,A,38 38 562 (KABUSHIKI KAISHA TOSHIBA) 24 May 1989 see claims ---	1-12
A	PATENT ABSTRACTS OF JAPAN vol. 17, no. 516 (C-1112) 17 September 1993 & JP,A,05 140 251 (SHOWA HIGHPOLYMER CO) 8 June 1993 see abstract ---	4-8
P,X	EP,A,0 570 094 (MORTON INTERNATIONAL) 18 November 1993 see the whole document -----	1-15

INTERNATIONAL SEARCH REPORT

Inter. Application No
PCT/GB 94/02258

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		BE-A- 804003	25-02-74
		CA-A- 1007098	22-03-77
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		FR-A,B 2197301	22-03-74
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